# NSN 5961-00-173-1129

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Inclosure Material:

Metal

**Overall Length:** 

0.340 inches

## **Overall Diameter:**

0.620 inches

# Mounting Facility Quantity:

2

## Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

## **Mounting Method:**

Unthreaded hole

## Features Provided:

Hermetically sealed case

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

140.0 collector to base voltage/static/emitter open and 120.0 collector to emitter voltage/static/base open and 8.0 emitter to base voltage, static, collector open

## **Current Rating Per Characteristic:**

2.00 amperes source cutoff current

## Power Rating Per Characteristic:

28.0 watts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: npn

## **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

No

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